Reg. No. :

Question Paper Code: 41023

B.E. / B.Tech. DEGREE EXAMINATION, MAY 2017

Second Semester

Civil Engineering

14UPH203 - MATERIAL SCIENCE

(Common to Mechanical Engineering)

(Regulation 2014)

Duration: Three hours

Maximum: 100 Marks

Answer ALL Questions

PART A - (10 x 1 = 10 Marks)

1. In the case of ______, the valence band and the conduction band overlap each other

(a) conductors (b) dielectrics (c) insulators (d) semiconductors

2. The valence electrons are ______ the nucleus and they are ______ bound.

(a) ionic (b) covalent (c) hydrogen (d) metallic

3. The pure Si and Ge Semiconducting materials have _____ bonds.

(a) intrinsic semiconductor (b) compound semiconductor

- (c) n-type semiconductor (d) p-type semiconductor
- 4. In N-type Semiconductor, the Fermi energy level (E_F) lies

(a) between E_c and E_D	(b) between E_c and E_v
(c) between E_D and E_v	(d) none of these

5. The property of magnetic materials of retaining magnetism after withdrawal of the magnetizing force is known as

(a) Retentivity (b) coercivity (c) reluctivity (d) conductivity

6.	The superconducting s	state is perfectly	in nature.					
	(a) Diamagnetic	(b) heat capacity	(c) isotopic effect	(d) entropy				
7.	occurs when a dielectric contains occluded gas bubbles.							
	(a) thermal break	lown	(b) defect breakdown	1				
	(c) intrinsic break	down	(d) discharge breakd	own				
8.	B Polarization occur in Ferrites and semiconductors.							
	(a) Electronic	(b) Ionic	(c) Orientation	(d) Space charge				
9.	Nitinol is a							
	(a) conducting pol	ymer	(b) electrets					
	(c) shape memory	alloy	(d) thermo electric m	naterial				
10. Milling, Lithographic method and machining are examples of								
	(a) bottom-up app	roach	(b) sputtering techni	que				
	(c) plasma assisted	l technique	(d) top-down approa	ch				
	PART - B (5 x $2 = 10$ Marks)							
11.	List the postulates of f	ree electron theory.						
12.	Compare intrinsic and	extrinsic semiconduc	ctor.					
13.	List the properties of a	Ferromagnetic mate	rial.					
14.	Define Dielectric cons	tant.						
15.	What is meant by glas	s transition temperatu	ire?					
		PART - C (5 x)	16 = 80 Marks)					
16.	(a) Derive an express Wiedemann- Fran		l and thermal conduct	ivity and hence de	duce (16)			
		0	r					
	(b) Derive an expression for density of states with a neat diagram. (16)							
17.	17. (a) Derive an expression for the density of holes in an intrinsic semiconductor. (16							
		0	Or					

(b) Derive an expression for the carrier concentration in a p-type semiconductor. (16)

18. (a) What are Ferrites? Classify Ferrites based on their structures.	(16)				
Or					
(b) Explain any four properties of Superconductors.	(16)				
19. (a) Interpret the different types of Polarization mechanism in dielectrics.	(16)				
Or					
(b) Deduce the Clausius-Mossotti equation.	(16)				
20. (a) Describe the preparation and properties of Metallic glasses.	(16)				
Or					
(b) Illustrate in detail the Sol-gel method to prepare nano material.	(16)				

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